

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L40	5724	(hole or via or opening or perforation).clm. and (fet or (field adj effect adj transistor)).clm.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/21 11:34
L41	800	(sense or sensing or sensed or sensor).clm. and (hole or via or opening or perforation).clm. and (fet or (field adj effect adj transistor)).clm.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/21 11:34
L42	293	(sense or sensing or sensed or sensor).clm. with (hole or via or opening or perforation).clm. and (fet or (field adj effect adj transistor)).clm.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/21 11:34
L43	50	(sense or sensing or sensed or sensor).clm. with (hole or via or opening or perforation).clm. with (fet or (field adj effect adj transistor)).clm.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/21 11:34
L44	1	(sense or sensing or sensed or sensor).clm. with (hole or via or opening or perforation).clm. with (fet or (field adj effect adj transistor)).clm. with contact.clm.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/21 11:35
L45	0	(sense or sensing or sensed or sensor).clm. with (hole or opening or perforation).clm. with (fet or (field adj effect adj transistor)).clm. with contact.clm.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/21 11:35
L46	16	(sense or sensing or sensed or sensor) with (hole or opening or perforation) with (fet or (field adj effect adj transistor)) with contact	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/21 11:37
L47	1589	((sense or sensing or sensed or sensor) with (hole or opening or perforation) with (contact)).clm.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/21 11:37
L48	10	((sense or sensing or sensed or sensor) with (hole or opening or perforation) with (contact)).clm. and (fet or (field adj effect adj transistor)).clm.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/21 11:39

L49	2	((sense or sensing or sensed or sensor) with (hole or opening or perforation) with (contact) with medium) and (fet or (field adj effect adj transistor)).clm.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/21 11:40
L50	7	((sense or sensing or sensed or sensor) with (hole or opening or perforation) with (contact) with medium) and (fet or (field adj effect adj transistor))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/21 11:49
L51	4	((sense or sensing or sensed or sensor) with (hole or opening or perforation) with (contact) with medium) and (fet or (field adj effect adj transistor)) and ((size or area) near10 (hole or opening))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/21 11:49